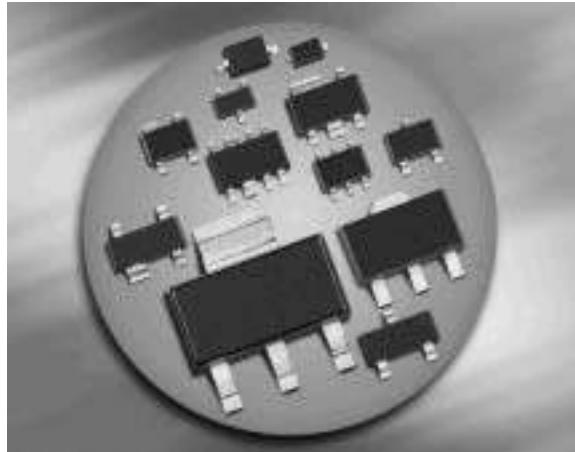
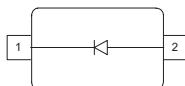


### Medium Power AF Schottky Diode

- Forward current: 1 A
- Reverse voltage: 30 V
- Low forward voltage, low reverse current
- For high efficiency DC/DC conversion, fast switching, protection and clamping applications
- Pb-free (RoHS compliant) package<sup>1)</sup>
- Qualified according AEC Q101



### BAS3010B-03W



Type	Package	Configuration	Marking
BAS3010B-03W	SOD323	single	2/ red

**Maximum Ratings** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage <sup>2)</sup>	$V_R$	30	V
Forward current <sup>2)</sup>	$I_F$	1	A
Average rectified forward current (50/60Hz, sinus)	$I_{FAV}$	1	
Repetitive peak forward current ( $t_p \leq 1 \text{ ms}$ , $D \leq 0.5$ )	$I_{FRM}$	3.5	
Non-repetitive peak surge forward current ( $t \leq 10 \text{ ms}$ )	$I_{FSM}$	10	
Junction temperature	$T_j$	150	$^\circ\text{C}$
Operating temperature range	$T_{op}$	-65 ... 125	
Storage temperature	$T_{stg}$	-65 ... 150	

<sup>1</sup>Pb-containing package may be available upon special request

<sup>2</sup> For  $T_A > 25^\circ\text{C}$  the derating of  $V_R$  and  $I_F$  has to be considered. Please refer to the attached curves.

**Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup>	$R_{thJS}$	$\leq 82$	K/W

**Electrical Characteristics** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

**DC Characteristics**

Reverse current <sup>2)</sup> $V_R = 5 \text{ V}$ $V_R = 10 \text{ V}$ $V_R = 30 \text{ V}$	$I_R$	-	-	5 10 20	$\mu\text{A}$
Forward voltage <sup>2)</sup> $I_F = 1 \text{ mA}$ $I_F = 10 \text{ mA}$ $I_F = 100 \text{ mA}$ $I_F = 500 \text{ mA}$ $I_F = 1 \text{ A}$	$V_F$	-	230 300 360 420 480	280 350 420 480 550	mV
		-	480	550	

**AC Characteristics**

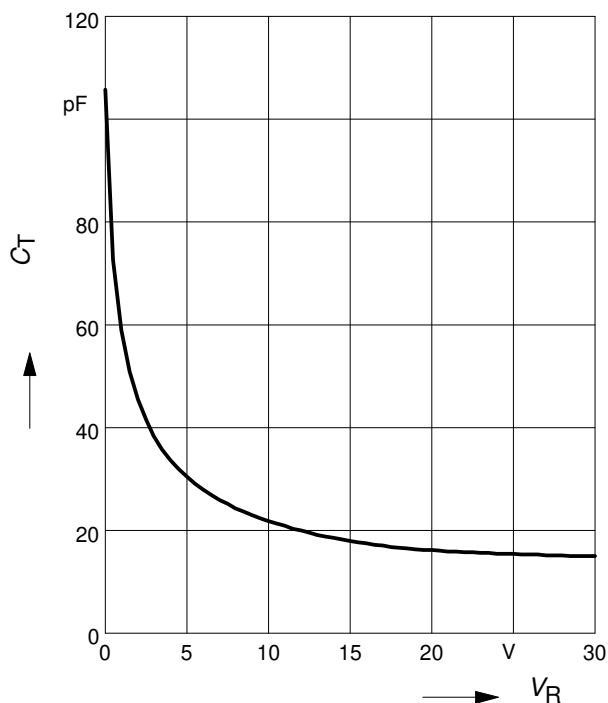
Diode capacitance $V_R = 5 \text{ V}, f = 1 \text{ MHz}$	$C_T$	-	33	40	pF
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<sup>1)</sup>For calculation of  $R_{thJA}$  please refer to Application Note Thermal Resistance

<sup>2)</sup>Pulsed test:  $t_p = 300 \mu\text{s}; D = 0.01$

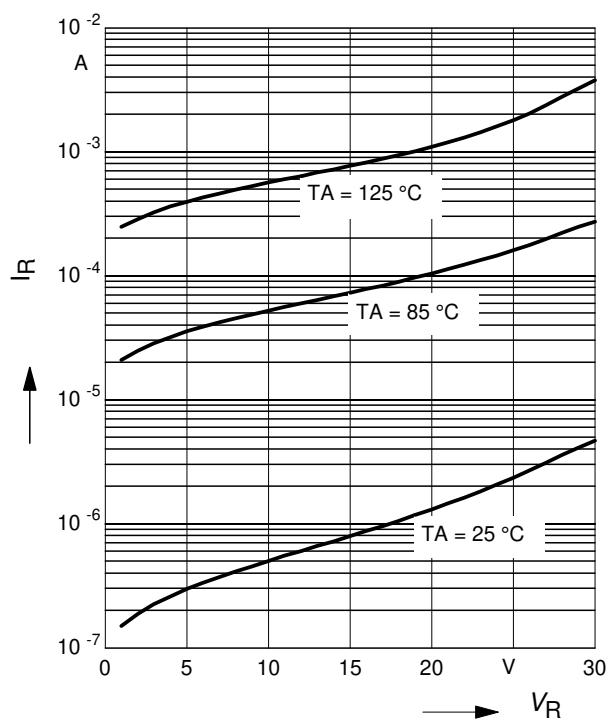
**Diode capacitance**  $C_T = f(V_R)$

$f = 1\text{MHz}$



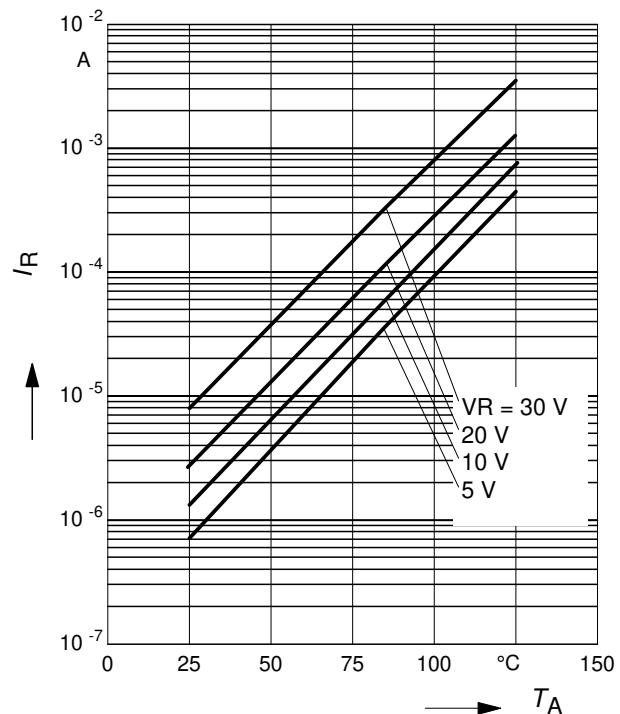
**Reverse current**  $I_R = f(V_R)$

$T_A$  = Parameter



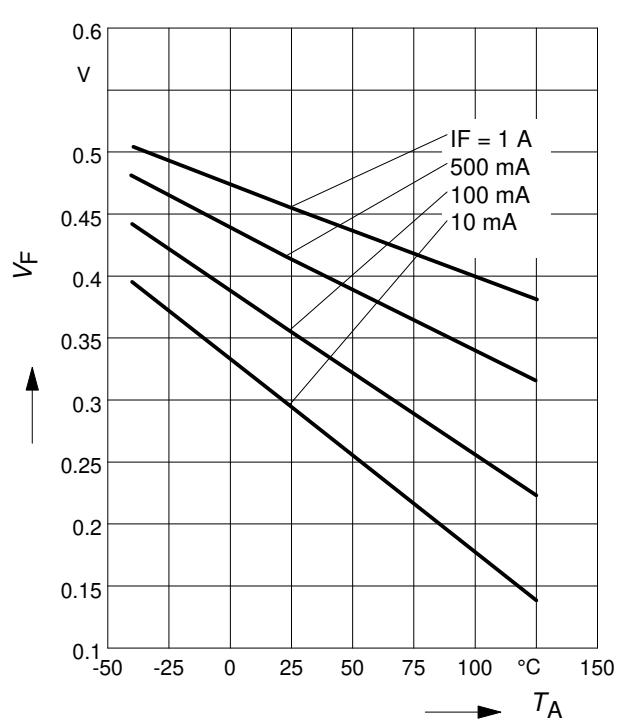
**Reverse current**  $I_R = f(T_A)$

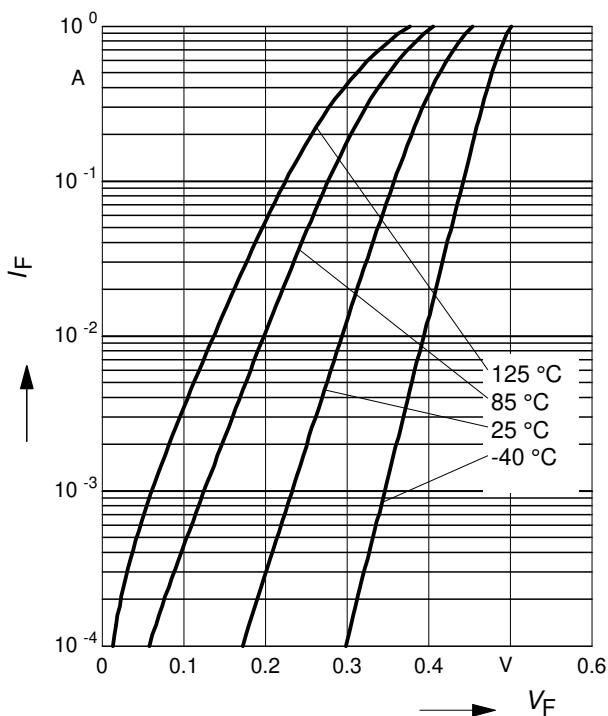
$V_R$  = Parameter



**Forward Voltage**  $V_F = f(T_A)$

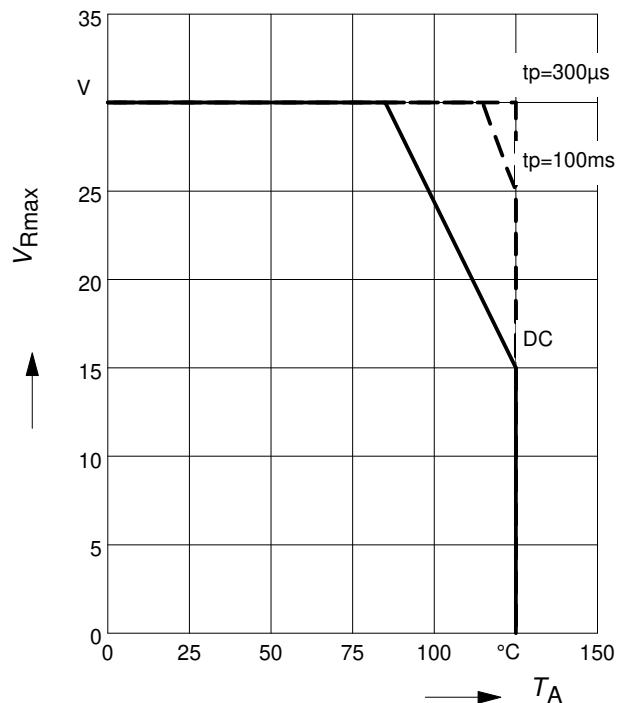
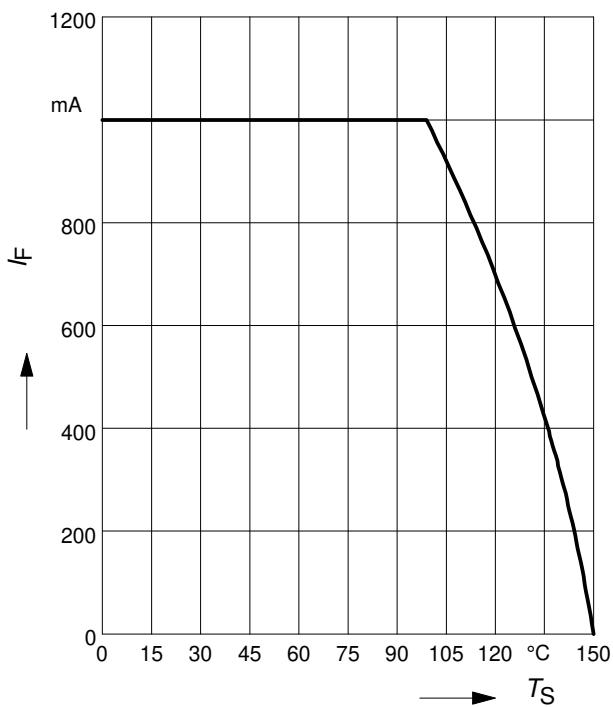
$I_F$  = Parameter



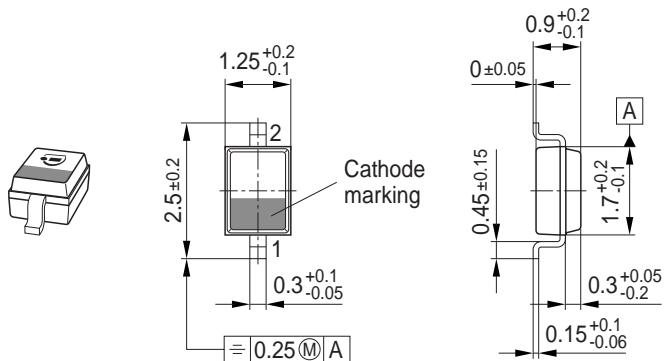
**Forward current  $I_F = f(V_F)$** 

**Permissible Reverse voltage  $V_R = f(T_A)$** 

$t_p$  = Parameter, Duty cycle < 0.01

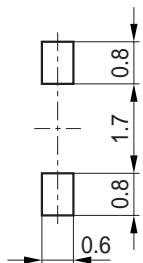
Device mounted on PCB with  $R_{th} = 160 \text{ k}\Omega\text{W}$


**Forward current  $I_F = f(T_S)$** 


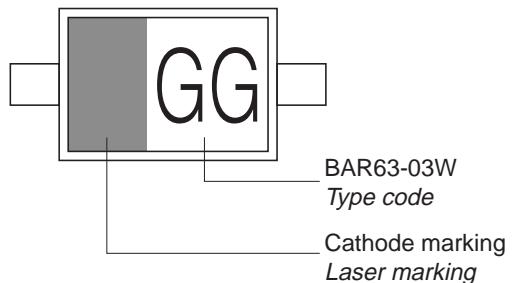
## Package Outline



## Foot Print

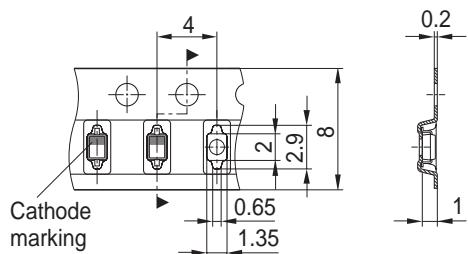


## Marking Layout (Example)



## Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel  
 Reel ø330 mm = 10.000 Pieces/Reel



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